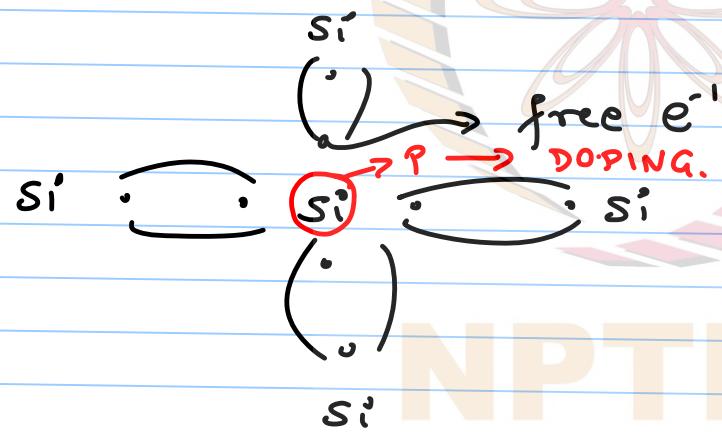


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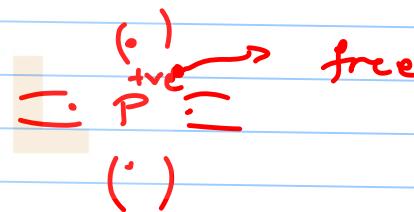
EE5311

MODULE - 1 THE TRANSISTOR



$$Si \text{ density} : 10^{22}/\text{cm}^3$$

$$\begin{aligned} @ \text{ Room Temp } (27^\circ\text{C}) &= n_i = p_i \\ &= 10^{10}/\text{cm}^3 \end{aligned}$$



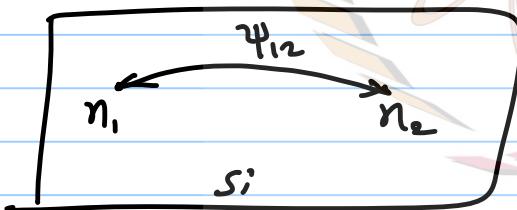
$$\begin{aligned} n &= N_D = \text{Doping Conc} \\ &\sim 10^{15}/\text{cm}^3 \end{aligned}$$

LAW OF MASS ACTION:

$$np = n_i^e$$

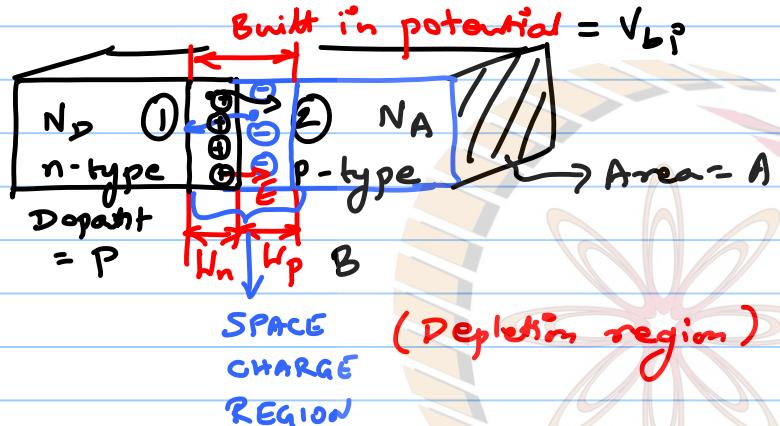
$$n = N_D$$

$$P = \frac{n_i^2}{N_D}$$



$$\frac{n_1}{n_2} = e^{\Psi_{12}/(kT/q)}$$

$$\frac{kT}{qV} @ RT = 25 \text{ mV}$$



$$q/N_D W_n \cdot A = q/W_p N_A \cdot A$$

$$\Rightarrow [W_n \cdot N_D = W_p N_A]$$

$$\text{if } N_D \gg N_A \\ \Rightarrow W_p \gg W_n$$

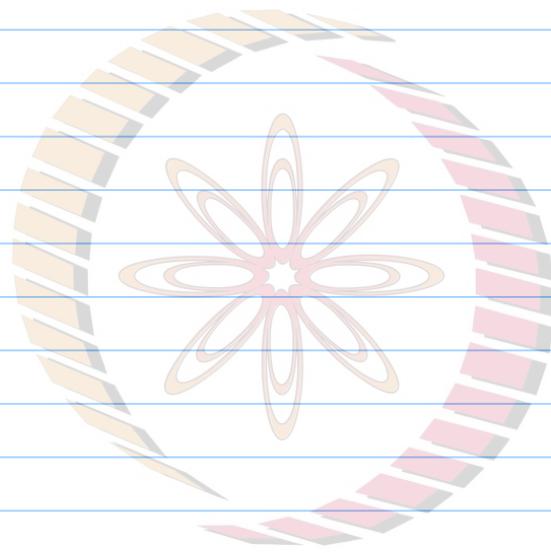
$$\frac{n_1}{n_2} = e^{\frac{qV_{bi}}{kT}}$$

$$n_1 = N_D$$

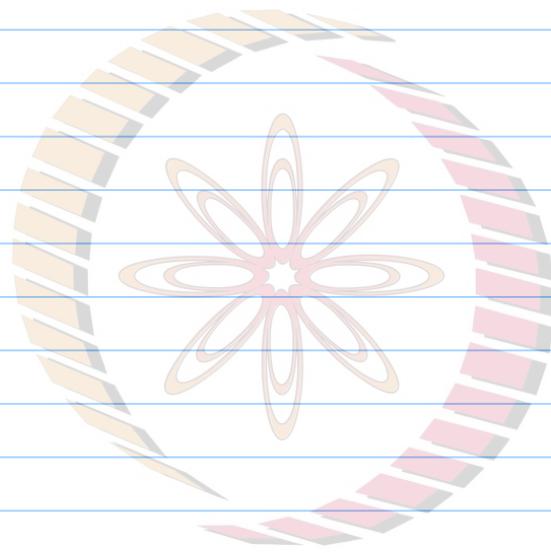
$$p_2 = N_A \\ \Rightarrow n_2 = \frac{n_i^2}{N_A}$$

$$\therefore \frac{N_D N_A}{n_i^2} = e^{\frac{qV_{bi}}{kT}}$$

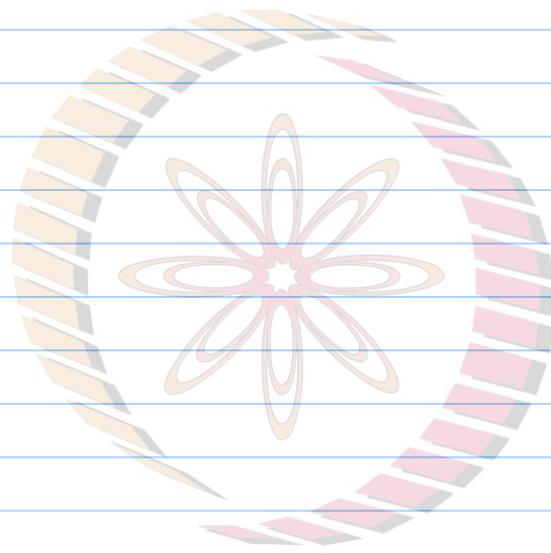
$$\therefore V_{bi} = \frac{kT}{q} \ln \left(\frac{N_A N_D}{n_i^2} \right)$$



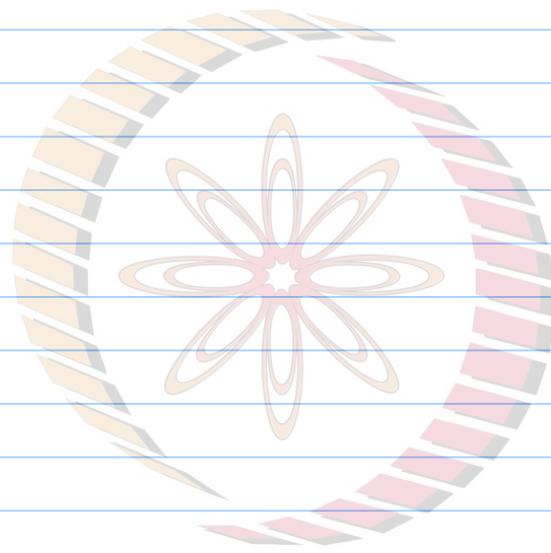
NPTEL



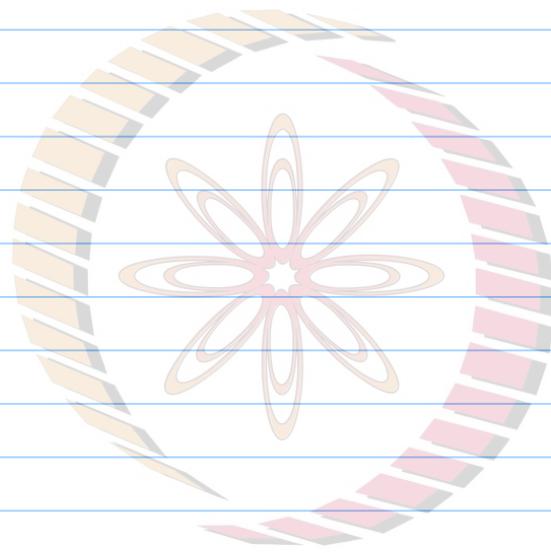
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NPTEL



NPTEL



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